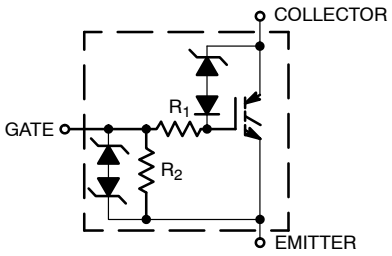
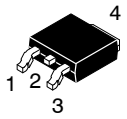
EcoSPARK® 2 Ignition IGBT

320 mJ, 450 V, N−Channel Ignition IGBT

FGD3245G2-F085V





DPAK (SINGLE GAUGE)
CASE 369C

Features

- SCIS Energy = 320 mJ at T_J = 25°C
- Logic Level Gate Drive
- Low Saturation Voltage
- AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant

Applications

- Automotive Ignition Coil Driver Circuits
- High Current Ignition System
- Coil on Plug Application

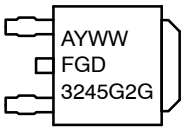
MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Symbol	Parameter	Value	Unit
BV_{CER}	Collector to Emitter Breakdown Voltage (IC = 1 mA)	450	V
BV_{ECS}	Emitter to Collector Voltage − Reverse Battery Condition (IC = 10 mA)	28	V
E_{SCIS25}	ISCIS = 14.6 A, L = 3.0 mHy, RGE = 1 KΩ, T_C = 25°C (Note 1)	320	mJ
$E_{SCIS150}$	ISCIS = 10.9 A, L = 3.0 mHy, RGE = 1 KΩ, T_C = 150°C (Note 2)	180	mJ
IC25	Collector Current Continuous at VGE = 4.0 V, T_C = 25°C	23	A
IC110	Collector Current Continuous at VGE = 4.0 V, T_C = 110°C	23	A
V_{GEM}	Gate to Emitter Voltage Continuous	±10	V
PD	Power Dissipation Total, T_C = 25°C	150	W
	Power Dissipation Derating, T_C > 25°C	1.1	W/°C
T_J, T_{STG}	Operating Junction and Storage Temperature	−55 to +175	°C
T_L	Lead Temperature for Soldering Purposes (1/8" from case for 10 s)	300	°C
T_{PKG}	Reflow Soldering according to JESD020C	260	°C
ESD	HBM−Electrostatic Discharge Voltage at 100 pF, 1500 Ω	4	kV
	CDM−Electrostatic Discharge Voltage at 1 Ω	2	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Self clamped inductive Switching Energy (ESCIS25) of 320 mJ is based on the test conditions that is starting T_J = 25°C, L = 3 mHy, ISCIS = 14.6 A, VCC = 100 V during inductor charging and VCC = 0 V during time in clamp.
2. Self Clamped inductive Switching Energy (ESCIS150) of 180 mJ is based on the test conditions that is starting T_J = 150°C, L = 3mHy, ISCIS = 10.9 A, VCC = 100 V during inductor charging and VCC = 0 V during time in clamp.

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
FGD3245G2= Device Code
G = Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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THERMAL RESISTANCE RATINGS

Characteristic	Symbol	Max	Units
Junction−to−Case − Steady State (Drain)	$R_{\theta JC}$	0.9	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min	Typ.	Max.	Units
OFF CHARACTERISTICS							
BV_{CER}	Collector to Emitter Breakdown Voltage	I_{CE} = 2 mA, V_{GE} = 0 V, R_{GE} = 1 kΩ, T_J = −40 to 150°C		420	−	480	V
BV_{CES}	Collector to Emitter Breakdown Voltage	I_{CE} = 10 mA, V_{GE} = 0 V, R_{GE} = 0, T_J = −40 to 150°C		440	−	500	V
BV_{ECS}	Emitter to Collector Breakdown Voltage	I_{CE} = −75 mA, V_{GE} = 0 V, T_J = 25°C		28	−	−	V
BV_{GES}	Gate to Emitter Breakdown Voltage	I_{GES} = ±2 mA		±12	±14	−	V
I_{CER}	Collector to Emitter Leakage Current	V_{CE} = 175 V, R_{GE} = 1 kΩ	T_J = 25°C	−	−	25	μA
			T_J = 150°C	−	−	1	
I_{ECS}	Emitter to Collector Leakage Current	V_{EC} = 24 V	T_J = 25°C	−	−	1	mA
			T_J = 150°C	−	−	40	
R_1	Series Gate Resistance			−	120	−	Ω
R_2	Gate to Emitter Resistance			10K	−	30K	Ω
ON CHARACTERISTICS							
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	I_{CE} = 6 A, V_{GE} = 4 V, T_J = 25°C		−	1.13	1.25	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	I_{CE} = 10 A, V_{GE} = 4.5 V, T_J = 150°C		−	1.32	1.50	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	I_{CE} = 15 A, V_{GE} = 5 V, T_J = 150°C		−	1.64	1.85	V
DYNAMIC CHARACTERISTICS							
$Q_{G(ON)}$	Gate Charge	I_{CE} = 10 A, V_{CE} = 12 V, V_{GE} = 5 V		−	23	−	nC
$V_{GE(TH)}$	Gate to Emitter Threshold Voltage	I_{CE} = 1 mA, V_{CE} = V_{GE}	T_J = 25°C	1.3	1.6	2.2	V
			T_J = 150°C	0.75	1.1	1.8	
V_{GEP}	Gate to Emitter Plateau Voltage	V_{CE} = 12 V, I_{CE} = 10 A		−	2.7	−	V
SWITCHING CHARACTERISTICS							
$td_{(ON)R}$	Current Turn−On Delay Time−Resistive	V_{CE} = 14 V, R_L = 1 Ω, V_{GE} = 5 V, R_G = 470 Ω, T_J = 25°C		−	0.9	4	μs
t_{rR}	Current Rise Time−Resistive			−	2.6	7	
$td_{(OFF)L}$	Current Turn−Off Delay Time−Inductive	V_{CE} = 300 V, L = 1 mH, V_{GE} = 5 V, R_G = 470 Ω, I_{CE} = 6.5 A, T_J = 25°C		−	5.4	15	
t_{fL}	Current Fall Time−Inductive			−	2.7	15	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Reel Diameter	Tape Width	Qty†
FGD3245G2	FGD3245G2−F085V	DPAK (Pb−Free)	330 mm	16 mm	2500

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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TYPICAL CHARACTERISTICS

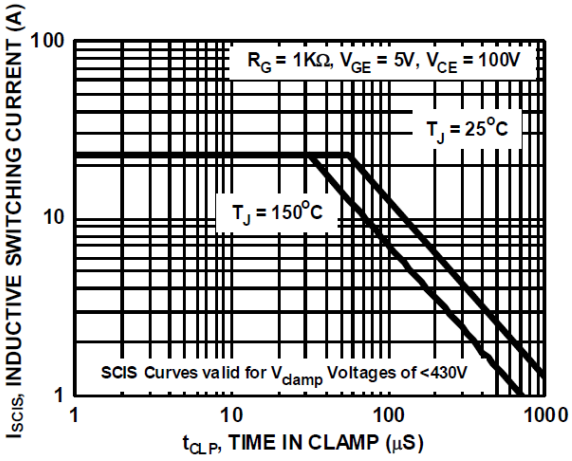


Figure 1. Self Clamped Inductive Switching Current vs. Time in Clamp

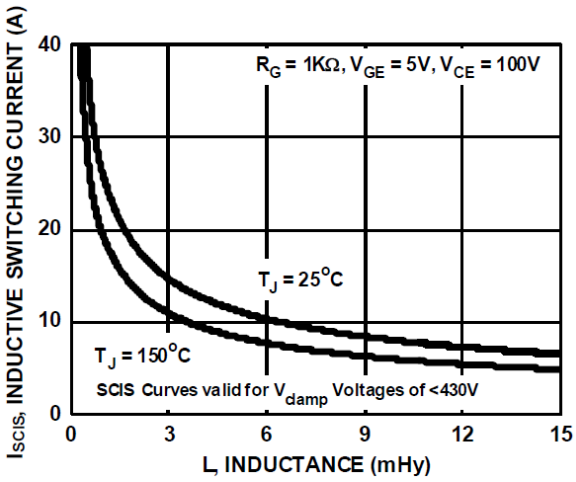


Figure 2. Self Clamped Inductive Switching Current vs. Inductance

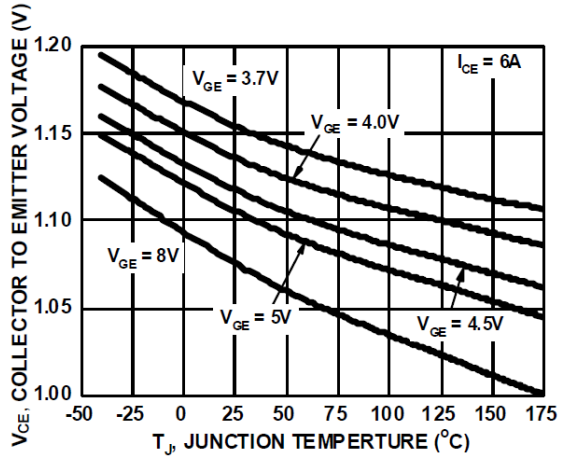


Figure 3. Collector to Emitter On−State Voltage vs. Junction Temperature

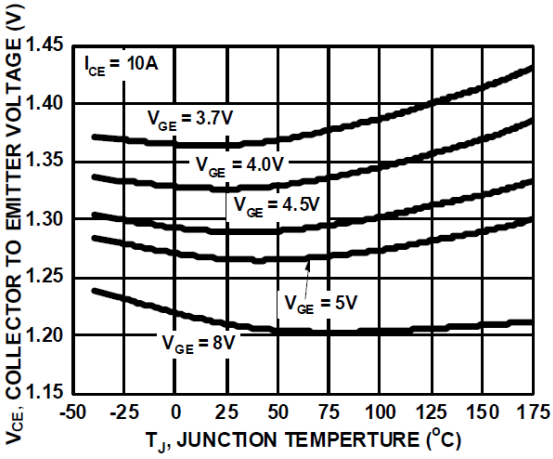


Figure 4. Collector to Emitter On−State Voltage vs. Junction Temperature

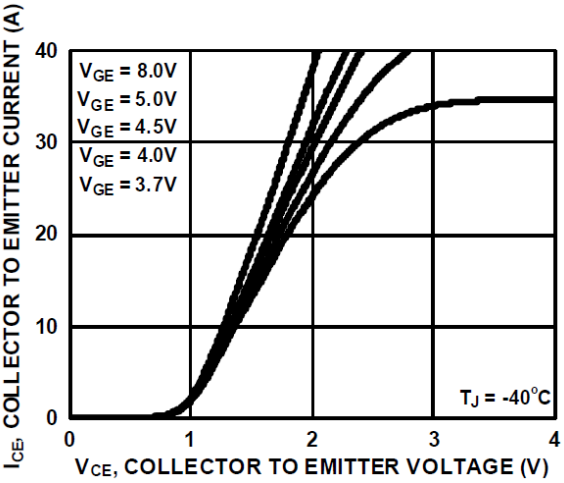


Figure 5. Collector to Emitter On−State Voltage vs. Collector Current

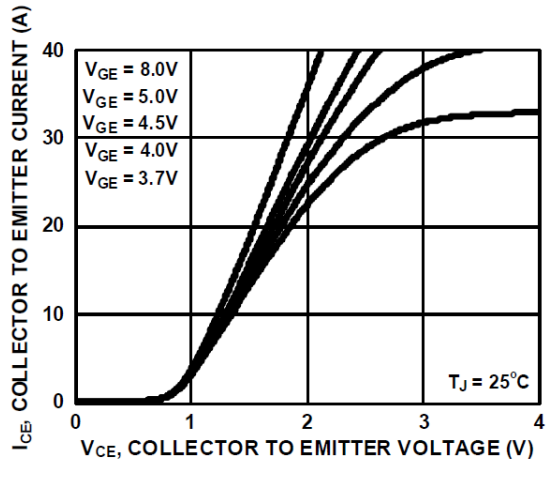


Figure 6. Collector to Emitter On−State Voltage vs. Collector Current

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TYPICAL CHARACTERISTICS (continued)

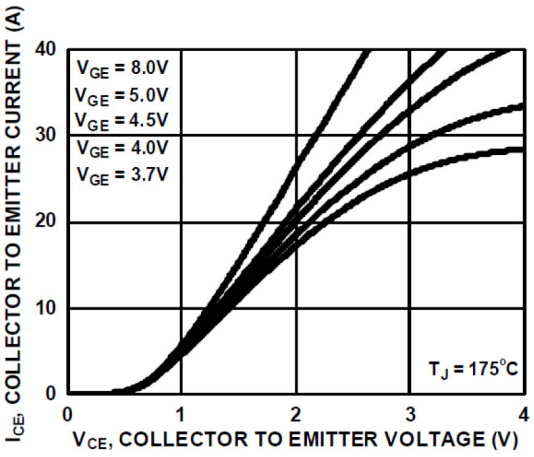


Figure 7. Collector to Emitter On−State Voltage vs. Collector Current

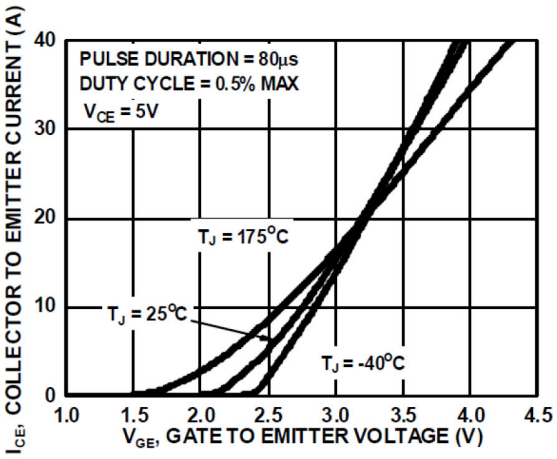


Figure 8. Transfer Characteristics

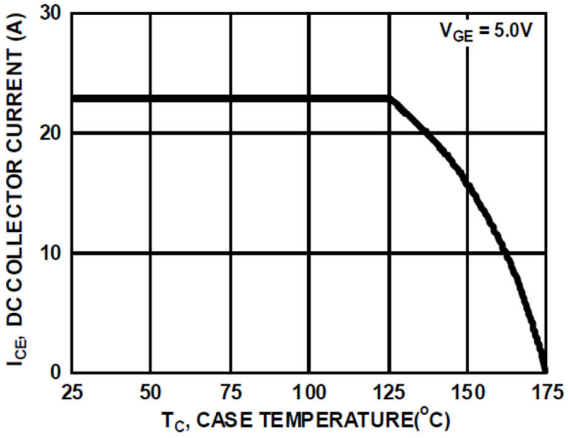


Figure 9. DC Collector Current vs. Case Temperature

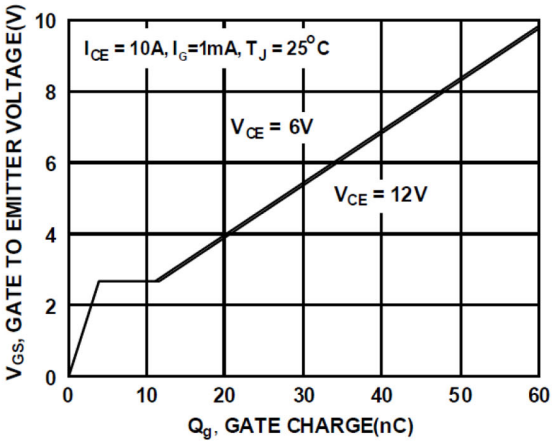


Figure 10. Gate Charge

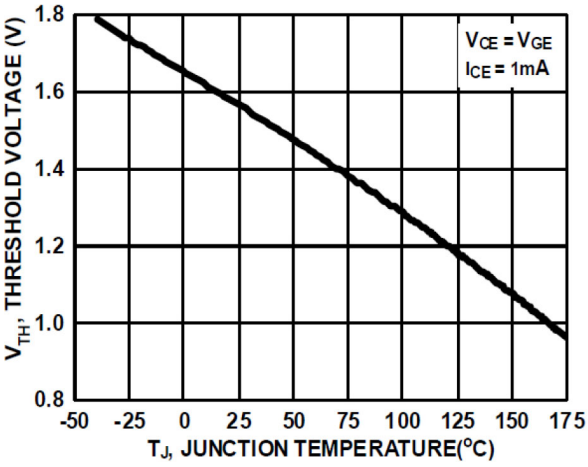


Figure 11. Threshold Voltage vs. Junction Temperature

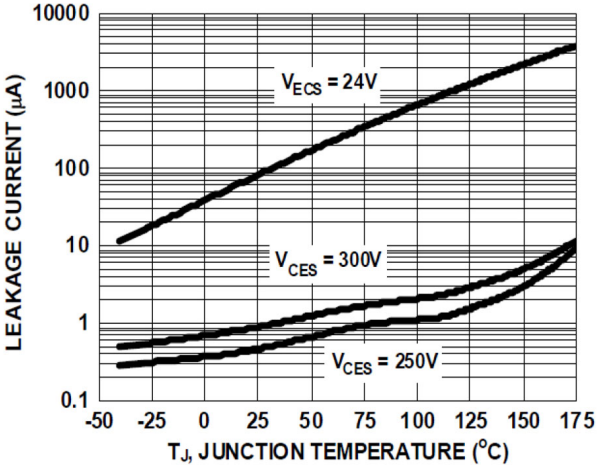


Figure 12. Leakage Current vs. Junction Temperature

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TYPICAL CHARACTERISTICS (continued)

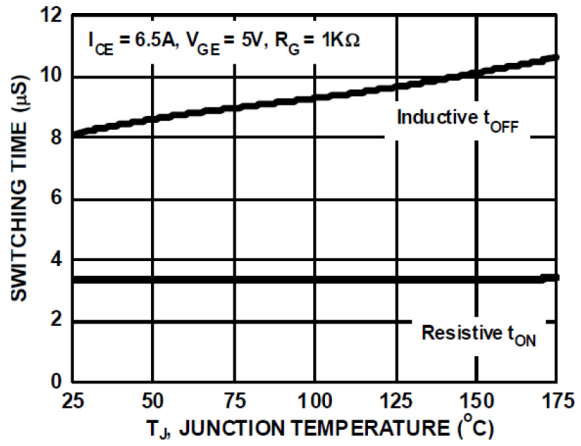


Figure 13. Switching Time vs. Junction Temperature

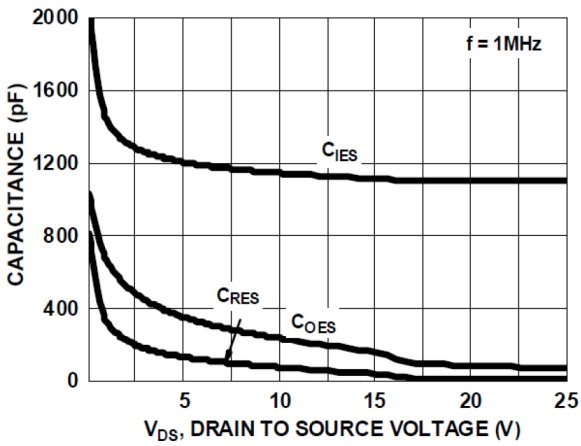


Figure 14. Capacitance vs. Collector to Emitter

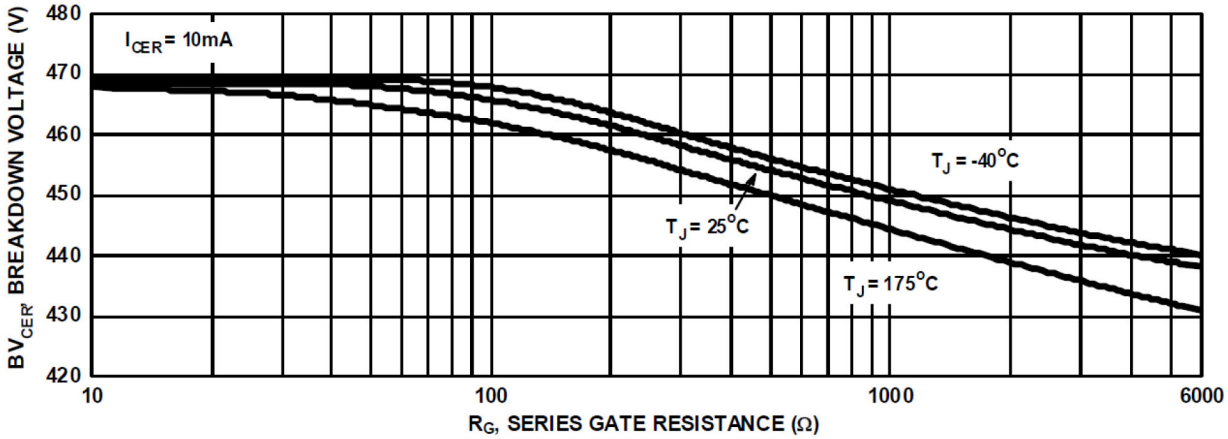


Figure 15. Break Down Voltage vs. Series Resistance

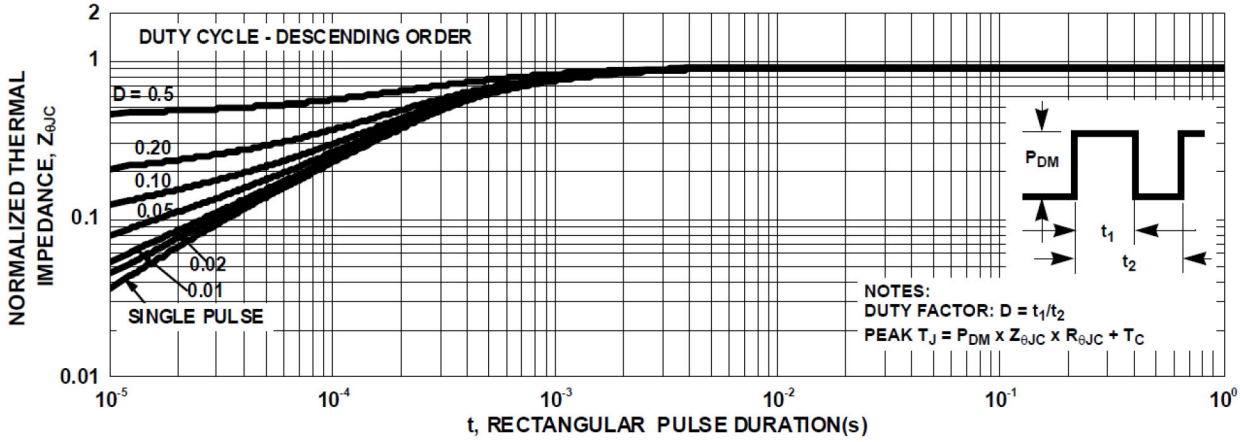


Figure 16. IGBT Normalized Transient Thermal Impedance, Junction to Case

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TEST CIRCUIT AND WAVEFORMS

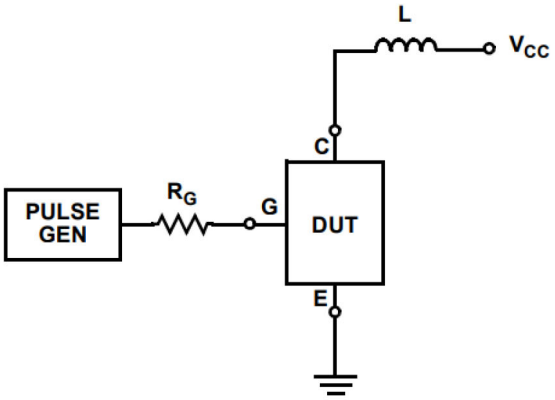


Figure 17. Inductive Switching Test Circuit

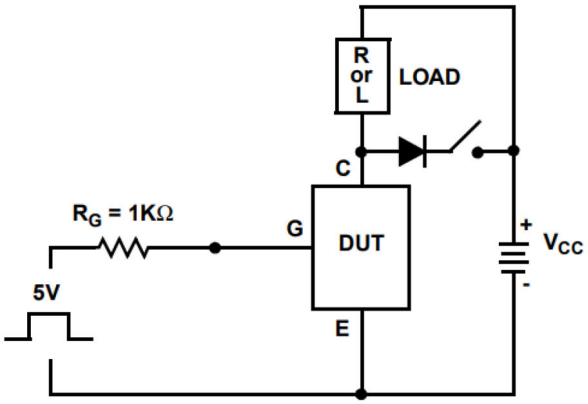


Figure 18. t_{ON} and t_{OFF} Switching Test Circuit

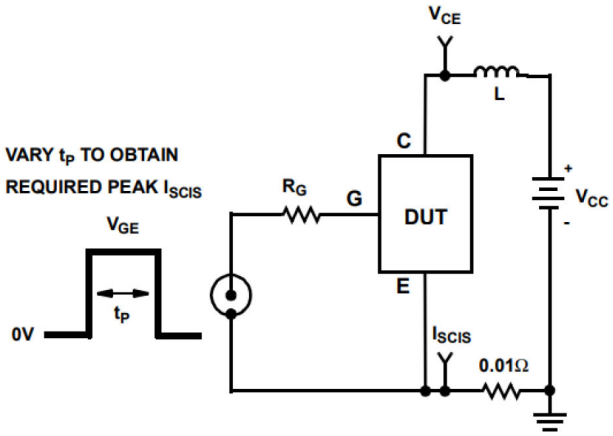


Figure 19. Energy Test Circuit

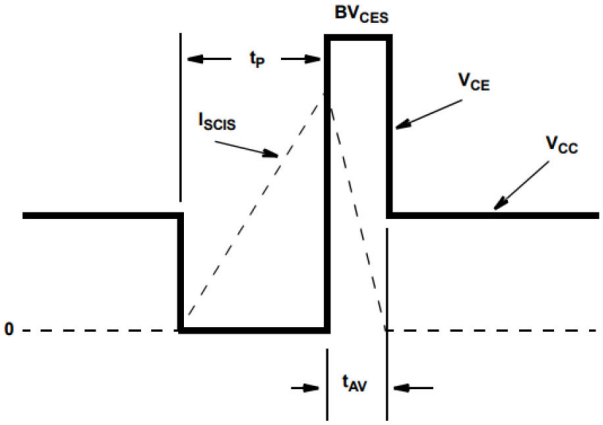
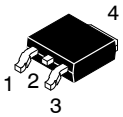


Figure 20. Energy Waveforms

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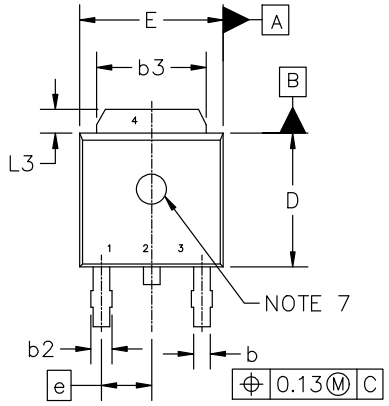
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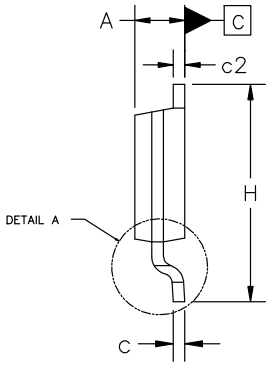
SCALE 1:1

DPAK−3 6.10x6.54x2.28, 2.29P
CASE 369C
ISSUE L

DATE 24 AUG 2026

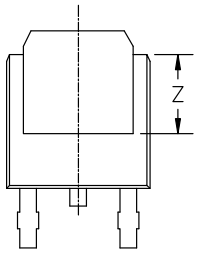


TOP VIEW

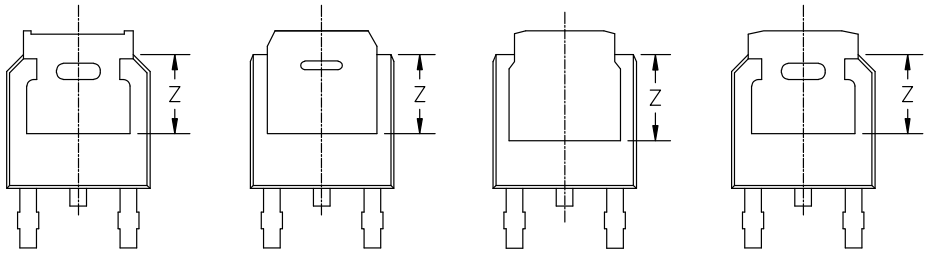


SIDE VIEW

MILLIMETERS			
DIM	MIN	NOM	MAX
A	2.18	2.28	2.38
A1	0.00	−−−	0.13
b	0.63	0.76	0.89
b2	0.72	0.93	1.14
b3	4.57	5.02	5.46
c	0.46	0.54	0.61
c2	0.46	0.54	0.61
D	5.97	6.10	6.22
E	6.35	6.54	6.73
e	2.29 BSC		
H	9.40	9.91	10.41
L	1.40	1.59	1.78
L1	2.90 REF		
L2	0.51 BSC		
L3	0.89	−−−	1.27
L4	−−−	−−−	1.01
Z	3.93	−−−	−−−



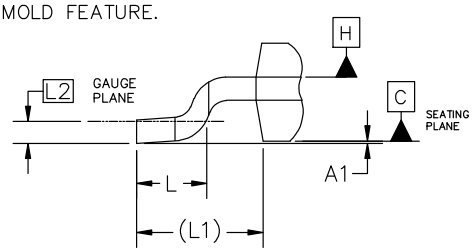
BOTTOM VIEW



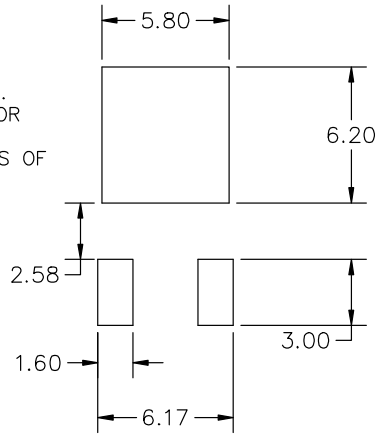
ALTERNATE CONSTRUCTIONS

NOTES:

1. DIMENSIONING AND TOLERANCING ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3, AND Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.



DETAIL A
ROTATED 90° CW



RECOMMENDED MOUNTING FOOTPRINT*
*For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques reference manual, SOLDERRM/D.

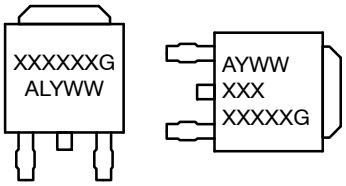
DOCUMENT NUMBER:	**98AON10527D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**DPAK−3 6.10x6.54x2.28, 2.29P**	**PAGE 1 OF 2**

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DPAK−3 6.10x6.54x2.28, 2.29P
CASE 369C
ISSUE L

DATE 24 AUG 2026

GENERIC MARKING DIAGRAM*



IC **Discrete**

XXXXXX	= Device Code
A	= Assembly Location
L	= Wafer Lot
Y	= Year
WW	= Work Week
G	= Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 3:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE

STYLE 4:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 5:
PIN 1. GATE
2. ANODE
3. CATHODE
4. ANODE

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

STYLE 7:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 8:
PIN 1. N/C
2. CATHODE
3. ANODE
4. CATHODE

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. RESISTOR ADJUST
4. CATHODE

STYLE 10:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

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